

## **LCD EMI Filter Array with ESD Protection**

#### **Features**

- · Six and eight channels of EMI filtering
- ±15kV ESD protection on each channel (IEC 61000-4-2 Level 4, contact discharge)
- ±30kV ESD protection on each channel (HBM)
- Better than 30dB of attenuation at 1GHz to 3GHz
- 15-bump, 2.960mm x 1.330mm footprint Chip Scale Package (CSPEMI606)
- 20-bump, 4.000mm x 1.458mm footprint Chip Scale Package (CSPEMI608)
- Chip Scale Package features extremely low lead inductance for optimum filter and ESD performance
- RoHS compliant (lead-free) finishing available

### **Applications**

- LCD data lines in clamshell wireless handsets
- EMI filtering & ESD protection for high-speed I/O data ports
- Wireless handsets / cell phones
- Notebook computers
- PDAs / Handheld PCs
- EMI filtering for high-speed data lines

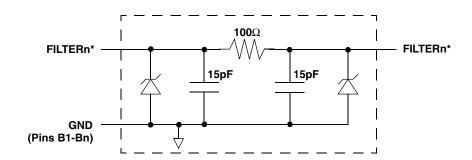
### **Product Description**

CMD's CSPEMI606 and CSPEMI608 are EMI filter arrays with ESD protection, which integrate six and eight Pi- filters (C-R-C), respectively. The CSPEMI60x has component values of 15pF-100 $\Omega$ -15pF. These devices include ESD protection diodes on every pin, which provide a very high level of protection for sensitive electronic components that may be subjected to electrostatic discharge (ESD). The ESD diodes connected to the filter ports are designed and characterized to safely dissipate ESD strikes of  $\pm$ 15kV, beyond the maximum requirement of the IEC 61000-4-2 international standard. Using the MIL-STD-883 (Method 3015) specification for Human Body Model (HBM) ESD, the pins are protected for contact discharges at greater than  $\pm$ 30kV.

These devices are particularly well suited for portable electronics (e.g. wireless handsets, PDAs, notebook computers) because of their small package format and easy-to-use pin assignments. They are ideal for EMI filtering and protecting data lines from ESD for the LCD display in clamshell handsets.

The CSPEMI606 and CSPEMI608 are available in space-saving, low-profile chip-scale packages.

### **Electrical Schematic**



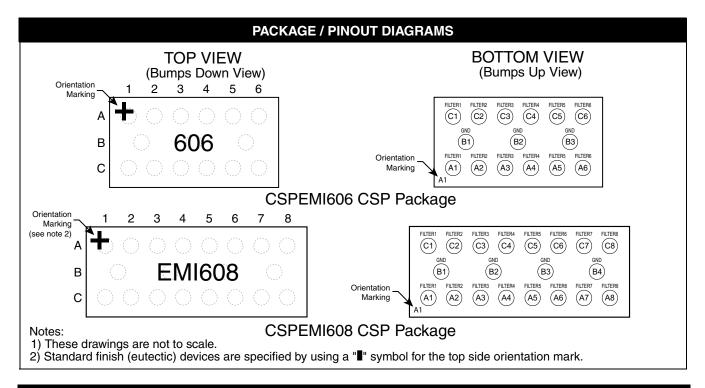
1 of 6 or 8 EMI Filtering + ESD Channels

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<sup>\*</sup> See Package/Pinout Diagram for expanded pin information.





	PIN DESCRIPTIONS										
CSPEMI606	CSPEMI608	NAME	DESCRIPTION		CSPEMI606	CSPEMI608	NAME	DESCRIPTION			
PIN(s)	PIN(s)	NAME	DESCRIPTION		PIN(s)	PIN(s)	NAME	DESCRIPTION			
A1	A1	FILTER1	Filter Channel 1		C1	C1	FILTER1	Filter Channel 1			
A2	A2	FILTER2	Filter Channel 2		C2	C2	FILTER2	Filter Channel 2			
A3	A3	FILTER3	Filter Channel 3		C3	C3	FILTER3	Filter Channel 3			
A4	A4	FILTER4	Filter Channel 4		C4	C4	FILTER4	Filter Channel 4			
A5	<b>A</b> 5	FILTER5	Filter Channel 5		C5	C5	FILTER5	Filter Channel 5			
A6	A6	FILTER6	Filter Channel 6		C6	C6	FILTER6	Filter Channel 6			
-	A7	FILTER7	Filter Channel 7		-	C7	FILTER7	Filter Channel 7			
-	A8	FILTER8	Filter Channel 8		-	C8	FILTER8	Filter Channel 8			
B1-B3	B1-B4	GND	Device Ground								

## **Ordering Information**

PART NUMBERING INFORMATION								
		Standard (Eu	tectic) Finish <sup>2</sup>					
Bumps	Package	Ordering Part Number <sup>1</sup>	Part Marking	Ordering Part Number <sup>1</sup>	Part Marking			
15	CSP	CSPEMI606G	606	_	_			
20	CSP	CSPEMI608G	EMI608	CSPEMI608 <sup>3</sup>	EMI608			

Note 1: Parts are shipped in Tape & Reel form unless otherwise specified.

Note 2: Standard finish (Eutectic) devices are specified by using a "I" symbol for the top side orientation mark.

Note 3: The Eutectic version of the CSPEMI608 is being obsoleted by end of Q2CY08.

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### **Specifications**

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	RATING	UNITS				
Storage Temperature Range	-65 to +150	°C				
DC Power per Resistor	100	mW				
DC Package Power Rating	500	mW				

STANDARD OPERATING CONDITIONS						
PARAMETER	RATING	UNITS				
Operating Temperature Range	-40 to +85	°C				

	ELECTRICAL O	PERATING CHARAC	TERIS	STICS	1	
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
R	Resistance		80	100	120	Ω
С	Capacitance	At 2.5V DC, 1MHz, 30mV AC	12	15	18	pF
V <sub>DIODE</sub>	Diode Standoff Voltage	I <sub>DIODE</sub> =10μA		6.0		V
I <sub>LEAK</sub>	Diode Leakage Current (reverse bias)	V <sub>DIODE</sub> =3.3V			200	nA
V <sub>SIG</sub>	Signal Voltage Positive Clamp Negative Clamp	I <sub>LOAD</sub> = 10mA	5.6 -1.5	6.8 -0.8	9.0 -0.4	V
V <sub>ESD</sub>	In-system ESD Withstand Voltage a) Human Body Model, MIL-STD-883, Method 3015 b) Contact Discharge per IEC 61000-4-2 Level 4	Notes 2,4 and 5	±30 ±15			kV kV
V <sub>CL</sub>	Clamping Voltage during ESD Discharge MIL-STD-883 (Method 3015), 8kV Positive Transients Negative Transients	Notes 2,3,4 and 5		+12 -7		V V
f <sub>C</sub>	Cut-off Frequency $Z_{SOURCE}$ =50 $\Omega$ $Z_{LOAD}$ =50 $\Omega$	R=100Ω C=15pF		120		MHz

Note 1: T<sub>A</sub>=25°C unless otherwise specified.

Note 2: ESD applied to input and output pins with respect to GND, one at a time.

Note 3: Clamping voltage is measured at the opposite side of the EMI filter to the ESD pin. For example, if ESD is applied to Pin A1, then clamping voltage is measured at Pin C1.

Note 4: Unused pins are left open

Note 5: These parameters are guaranteed by design and characterization.

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### **Performance Information**

Typical Filter Performance (T<sub>A</sub>=25°C, DC Bias=0V, 50 Ohm Environment)

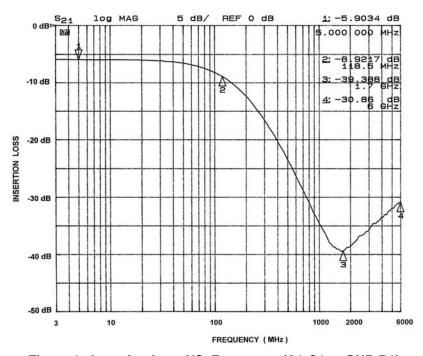


Figure 1. Insertion Loss VS. Frequency (A1-C1 to GND B1)

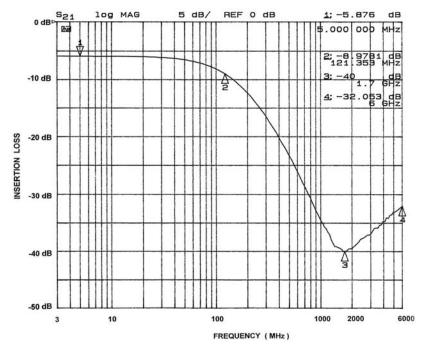


Figure 2. Insertion Loss VS. Frequency (A2-C2 to GND B1)

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Typical Filter Performance (T<sub>A</sub>=25°C, DC Bias=0V, 50 Ohm Environment)

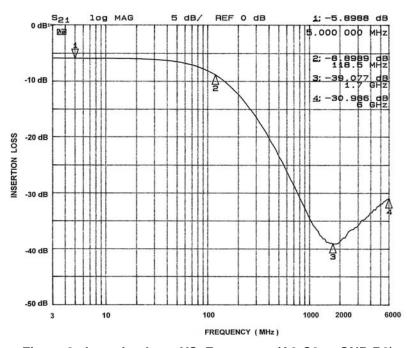


Figure 3. Insertion Loss VS. Frequency (A3-C3 to GND B2)

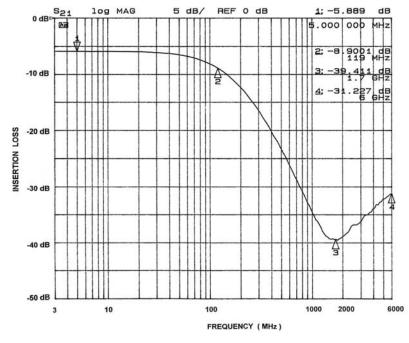


Figure 4. Insertion Loss VS. Frequency (A4-C4 to GND B2)

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Typical Filter Performance (T<sub>A</sub>=25°C, DC Bias=0V, 50 Ohm Environment)

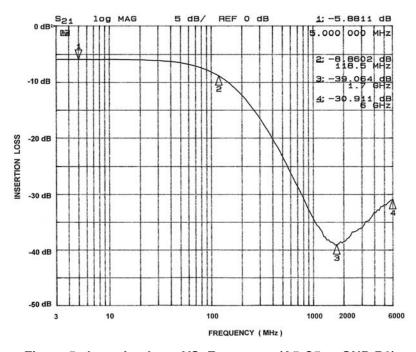


Figure 5. Insertion Loss VS. Frequency (A5-C5 to GND B3)

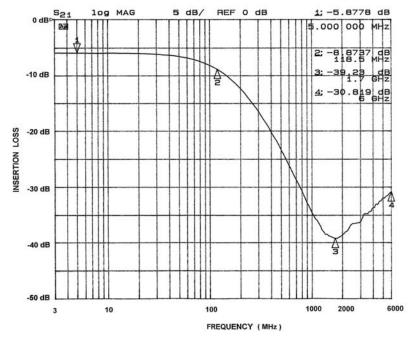


Figure 6. Insertion Loss VS. Frequency (A6-C6 to GND B3)

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Typical Filter Performance (T<sub>A</sub>=25°C, DC Bias=0V, 50 Ohm Environment)

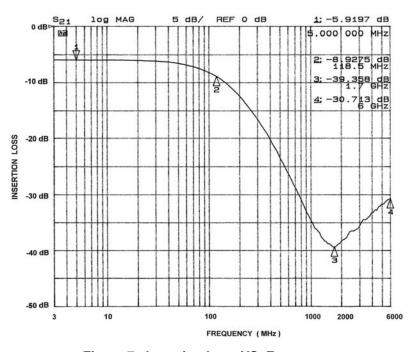


Figure 7. Insertion Loss VS. Frequency (A7-C7 to GND B4, CSPEMI608 Only)

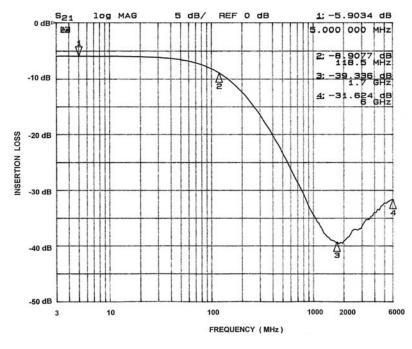


Figure 8. Insertion Loss VS. Frequency (A8-C8 to GND B4, CSPEMI608 Only)

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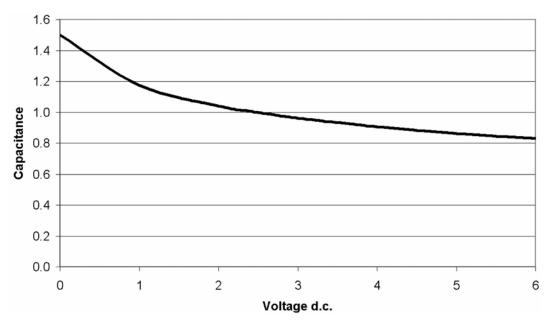


Figure 9. Filter Capacitance vs. Input Voltage over Temperature (normalized to capacitance at 2.5VDC and 25°C)



## **Application Information**

Refer to Application Note AP-217, "The Chip Scale Package", for a detailed description of Chip Scale Packages offered by California Micro Devices.

PRINTED CIRCUIT BOARD RECOMMENDATIONS							
PARAMETER	VALUE						
Pad Size on PCB	0.275mm						
Pad Shape	Round						
Pad Definition	Non-Solder Mask defined pads						
Solder Mask Opening	0.325mm Round						
Solder Stencil Thickness	0.125mm - 0.150mm						
Solder Stencil Aperture Opening (laser cut, 5% tapered walls)	0.330mm Round						
Solder Flux Ratio	50/50 by volume						
Solder Paste Type	No Clean						
Pad Protective Finish	OSP (Entek Cu Plus 106A)						
Tolerance — Edge To Corner Ball	<u>+</u> 50μm						
Solder Ball Side Coplanarity	<u>+</u> 20μm						
Maximum Dwell Time Above Liquidous	60 seconds						
Maximum Soldering Temperature for Eutectic Devices using Eutectic Solder Paste	240°C						
Maximum Soldering Temperature for Lead-free Devices using Lead-free Solder Paste	260°C						

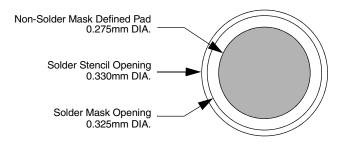


Figure 10. Recommended Non-Solder Mask Defined Pad Illustration

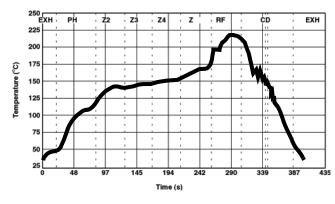


Figure 11. Eutectic (SnPb) Solder Ball Reflow Profile

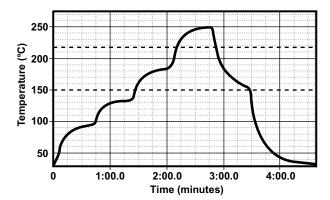


Figure 12. Lead-free (SnAgCu) Solder Ball Reflow Profile

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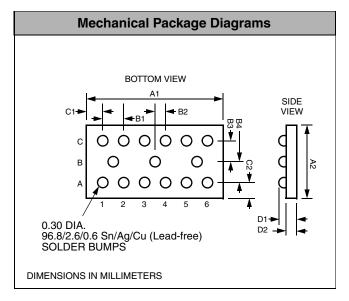
### **Mechanical Details**

The CSPEMI606/608 is supplied in custom Chip Scale Packages (CSP). Dimensions are presented below.

#### **CSPEMI606 Mechanical Specifications**

The package dimensions for the CSPEMI606 are presented below.

PACKAGE DIMENSIONS								
Pack	age	Custom CSP						
Bum	ıps			15				
Dim	M	lillimete	rs		Inches			
Dilli	Min	Nom	Max	Min	Nom	Max		
A1	2.915	2.960	3.005	0.1148	0.1165	0.1183		
A2	1.285	1.330	1.375	0.0506	0.0524	0.0541		
B1	0.495	0.500	0.505	0.0195	0.0197	0.0199		
B2	0.245	0.250	0.255	0.0096	0.0098	0.0100		
В3	0.430	0.435	0.440	0.0169	0.0171	0.0173		
B4	0.430	0.435	0.440	0.0169	0.0171	0.0173		
C1	0.180	0.230	0.280	0.0071	0.0091	0.0110		
C2	0.180	0.230	0.280	0.0071	0.0091	0.0110		
D1	0.561	0.605	0.649	0.0221	0.0238	0.0256		
D2	0.355	0.380	0.405	0.0140	0.0150	0.0160		
# per tap		3500 pieces						
	Controlling dimension: millimeters							



Package Dimensions for CSPEMI606 Chip Scale Package

#### **CSP Tape and Reel Specifications**

PART NUMBER	CHIP SIZE (mm)	POCKET SIZE (mm) B <sub>0</sub> X A <sub>0</sub> X K <sub>0</sub>	TAPE WIDTH W	REEL DIAMETER	QTY PER REEL	P <sub>0</sub>	P <sub>1</sub>
CSPEMI606	2.96 X 1.33 X 0.605	3.10 X 1.45 X 0.74	8mm	178mm (7")	3500	4mm	4mm

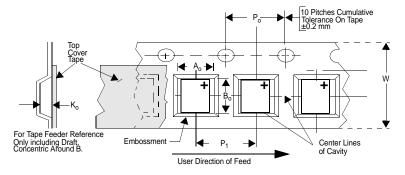


Figure 13. Tape and Reel Mechanical Data

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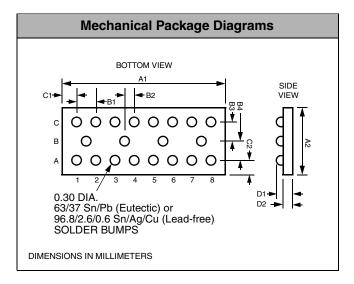


### **Mechanical Details (cont'd)**

#### **CSPEMI608 Mechanical Specifications**

The package dimensions for the CSPEMI608 are presented below.

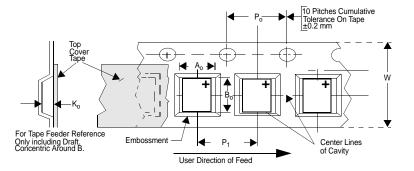
PACKAGE DIMENSIONS								
Pack	age	Custom CSP						
Bun	ıps			20				
Dim	M	lillimete	rs		Inches			
Dilli	Min	Nom	Max	Min	Nom	Max		
A1	3.955	4.000	4.045	0.1557	0.1575	0.1593		
A2	1.413	1.458	1.503	0.0556	0.0574	0.0592		
B1	0.495	0.500	0.505	0.0195	0.0197	0.0199		
B2	0.245	0.250	0.255	0.0096	0.0098	0.0100		
В3	0.430	0.435	0.440	0.0169	0.0171	0.0173		
B4	0.430	0.435	0.440	0.0169	0.0171	0.0173		
C1	0.200	0.250	0.300	0.0079	0.0098	0.0118		
C2	0.244	0.294	0.344	0.0096	0.0116	0.0135		
D1	0.561	0.605	0.649	0.0221	0.0238	0.0256		
D2	0.355	0.380	0.405	0.0140	0.0150	0.0160		
# per ta red		3500 pieces						
	Con	trolling o	dimensio	n: millim	eters			



Package Dimensions for CSPEMI608 Chip Scale Package

### **CSP Tape and Reel Specifications**

PART NUMBER	CHIP SIZE (mm)	POCKET SIZE (mm) B <sub>0</sub> X A <sub>0</sub> X K <sub>0</sub>	TAPE WIDTH W	REEL DIAMETER	QTY PER REEL	P <sub>0</sub>	P <sub>1</sub>
CSPEMI608	4.00 X 1.46 X 0.605	4.11 X 1.57 X 0.76	8mm	178mm (7")	3500	4mm	4mm



Note: Eutectic devices are specified by using a "I" symbol for the top side orientation mark.

Figure 14. Tape and Reel Mechanical Data

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